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# Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

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Office Action Summary		Application No.	Applicant(s)				
		10/753,524	YAMAZAKI ET AL.				
		Examiner	Art Unit				
		JOHANNES P. MONDT	3663				
Period fo	The MAILING DATE of this communication apor Reply	opears on the cover sheet with the c	orrespondence address				
WHIC - Exte after - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR REPLICATION OF THE MAILING INSURANCE IS LONGER, FROM THE MAILING INSURANCE IN THE MAILING IN THE MAILI	DATE OF THIS COMMUNICATION 136(a). In no event, however, may a reply be tind will apply and will expire SIX (6) MONTHS from te, cause the application to become ABANDONE	N. nely filed the mailing date of this communication. ED (35 U.S.C. § 133).				
Status							
1)  \	Responsive to communication(s) filed on 26 /	August 2008					
•	This action is <b>FINAL</b> . 2b) ☐ This action is non-final.						
3)□	, <del></del>						
٥)ا	closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
	·	Exparto gaayro, 1000 C.B. 11, 10	50 0.0.210.				
Disposit	ion of Claims						
4)🛛	Claim(s) <u>21-23,25,42-64 and 68-70</u> is/are pending in the application.						
	4a) Of the above claim(s) is/are withdrawn from consideration.						
5)	Claim(s) is/are allowed.						
6)🖂	6) Claim(s) <u>21-23, 25, 42-64 and 68-70</u> is/are rejected.						
7)							
8)□	Claim(s) are subject to restriction and/	or election requirement.					
Applicat	ion Papers						
9) ☐ The specification is objected to by the Examiner.							
-	The drawing(s) filed on is/are: a) ac		Examiner.				
<i>′</i> —	Applicant may not request that any objection to the						
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).							
11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.							
·	under 35 U.S.C. § 119						
	-	n muianitra unadan 25 H.C.C. S. 110/a	\				
	Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).						
а)	a)☑ All b)☐ Some * c)☐ None of:  1.☑ Certified copies of the priority documents have been received.						
	2. Certified copies of the priority documents have been received in Application No						
	3. Copies of the certified copies of the priority documents have been received in this National Stage						
	application from the International Bureau (PCT Rule 17.2(a)).						
* See the attached detailed Office action for a list of the certified copies not received.							
Attachmen	at(s)	_					
1) Notice of References Cited (PTO-892)  4) Interview Summary (PTO-413)							
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)  3) Information Disclosure Statement(s) (PTO/SB/08)  Paper No(s)/Mail Date  Notice of Informal Patent Application							
Paper No(s)/Mail Date 6) Other:							

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#### **DETAILED ACTION**

# Response to Amendment

1. Amendment filed 8/26/08 forms the basis for the Office action. In said

Amendment applicants substantially amended all pending claims through substantial

amendment of all independent claims. Comments on Remarks submitted with said

Amendment are included below under "Response to Arguments".

### Response to Arguments

2. Applicant's arguments filed 8/26/08 have been fully considered but they are not persuasive. In particular, applicant's only argument of traverse is based on the newly introduced claim limitation "wherein first lattice images in a direction parallel to said grain boundary in the first crystal are different from second lattice images in the direction parallel to said grain boundary in the second crystal". However, "lattice images" cannot be part of the claimed "personal computer", unless the personal computer contains said images on its memory space, which has not been disclosed in the Specification. The now claimed "images" are achieved by external means and do not belong to the "personal computer". Apparently, applicant on the one hand claims a "personal computer", but on the other hand claims a combination including said personal computer and first and second lattice images. This raises considerable confusion on whether the claims are directed to a sub-combination (personal computer) or the now recited combination (of personal computer and first and second lattice images). Therefore, the claims stand rejected over 35 U.S.C. 112, 1st and 2nd paragraph (first, because the now claimed "first and second lattice images" were not disclosed to

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be part of the personal computer, and second because it is not clear from the current claim language whether a combination or a sub-combination is claimed: the sub-combination being indicated through the pre-amble, yet the bulk of the claim now drawn to what appears to be a combination of personal computer and said images.

Furthermore, nothing ordains either the quality or the resolution power of said images. The HRTEM does not define said resolution, but instead only narrows said resolution to a broad and indefinite range, as explained earlier.

Even arguendo, when two different abutting crystals are being imaged, their images differ because two distinct images will appear unless the imaging is absolutely flawed by given indefinite images. Therefore, any given set of images of the first and second crystal inherently are different in that said images show different crystals.

Therefore, the claims still stand rejected over prior art previously cited.

#### Claim Rejections - 35 USC § 112

3. The following is a quotation of the first paragraph of 35 U.S.C. 112:

The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.

4. Claims 21-23, 25, 42-64 and 68-70 are rejected under 35 U.S.C. 112, first paragraph, as failing to comply with the written description requirement. The claims contain subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventors, at the time the application was filed, had possession of the claimed invention. Within the context of the claimed "personal computer" the limitations "wherein first lattice images in a direction

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parallel to said grain boundary in the first crystal are different from second lattice images in the direction parallel to said grain boundary in the second crystal" (claim 21, lines 11-13; claim 46, lines 12-14; and claim 56, lines 12-14) has not been disclosed in the original specification. That images may be made of lattices at a grain boundary of a semiconductor film in said personal computer is a different matter altogether. Said images are simply not part of the personal computer, nor are they inherently determined by any component of said personal computer as disclosed. Therefore, said limitations constitute new matter.

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- 5. The following is a quotation of the second paragraph of 35 U.S.C. 112:
  The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.
- 6. Claims 21-23, 25, 42-64 and 68-70 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention. The noted introduction of new matter (see section 4 above) implies a lack of adequate written description in support of the claimed invention, as a result of which the metes and bounds of the claimed invention are vague and ill-defined, rendering the claims indefinite.
- 7. Claims 21-23, 25, 42-64 and 68-70 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention. In amended form the claims are on the one hand drawn to a "personal computer" in light of the pre-amble, yet appear to be drawn by amendment to a combination of "personal computer" and "first lattice images" and "second lattice images", because a reasonable interpretation of the

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specification precludes said first and second lattice images to be disclosed as part of the personal computer. All claims are thus seen to be indefinite, being drawn to a device of which the scope is indefinite, being either a combination or sub-combination.

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# Claim Rejections - 35 USC § 102

8. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 9. N.B.: The rejections under 35 U.S.C. 102(e) and 103(a) are provided subject to the aforementioned indefiniteness under 35 U.S.C. 112, second paragraph, assuming that images are different when they show different objects, and assuming that the claims are drawn to the previously elected sub-combination (personal computer; as otherwise a non-responsive would have been issued).
- 10. Claim 21, 42- 43, 47 and 51-52 are rejected under 35 U.S.C. 102(e) as being anticipated by Iwasaki (JP 08-288515 A) (previously cited, with family member Iwasaki (USPAT 5,759,879) serving again as translation).
- 11. *Iwasaki teaches* (whole document, especially title, abstract, "Field of the Invention", column 1, lines 7-20, and Examples 1-2, columns 7-12; Figures 2-3) a semiconductor film 22 (column 10, lines 45-48) over a substrate 16 (loc.cit.) and comprising a source region and drain region (both 26N; see column 10, line 50) and a

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channel formation region 26i (column 10, lines 49-50) provided between said source and drain regions; and a gate electrode 25 (column 10, line 55) provided adjacent to said channel formation region with a gate insulating film 24 (column 10, line 54) therebetween; wherein lattices are continuously connected to each other at a grain boundary 23 (Figure 3F and column 12, lines 17-18) of said semiconductor film, inherently so, because a grain boundary is a boundary, i.e., a line, point or plane that indicates or fixes a limit or extent, between two grains, i.e., crystal grains; said crystal grains inherently having spatial extent, as otherwise their defining property, i.e., spatial periodicity, could not possibly exist; the lines denoting the grain boundaries in Figure 3F thus denote the limits on either side of the crystal grains connected by their common grain boundaries, implying continuity across said grain boundaries; hence the lattices of said grains, extending by definition of the grains over their entire spatial domain, are continuously connected to each other at the grain boundaries of said semiconductor film.

With regard to the claimed "first lattice images in a direction parallel to said grain boundary in the first crystal" being different from "second lattice images in the direction parallel to said grain boundary", said limitation fails to further limit the claimed "personal computer": although the claimed "first lattice images" and "second lattice images" are not necessarily taught by the prior art, said images do not belong to the claimed "personal computer" as disclosed, while any images made of said first and second lattices in the same direction parallel to the grain boundary, when made, necessarily differ because said first lattice and second lattices differ if only by being in different

crystals, and hence they are distinguishable given any adequate images of said first and second lattices.

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With regard to claim 42, the direction of movements of any of the (charge) carriers has inherently two components, a random component and a component in response to the local (mainly electric) field. While the direction of said random component by its very nature is not subject to control, the component in response to the local field is a result of the operation of the device, and hence is not a limitation of the device as such.

Therefore, the limitation on the direction of movement of a carrier in said channel formation region is a statement of intended use not serving to patently distinguish the claimed structure over that of the reference as long as the structure of the cited reference is capable of performing the intended use. See MPEP 2111-2115. See also MPEP 2114 that states:

"A claim that contains a "recitation with respect to the manner in which a claimed apparatus is intended to be employed does not differentiate the claimed apparatus from a prior art apparatus" if the prior art apparatus teaches all of the structural limitations of the claim Ex parte Masham, 2 USPQd 1647.".

"Claims directed to apparatus must be distinguished from the prior art in terms of structure rather than function. In re Danly, 263 F.2d 844, 847, 120 USPQ 528, 531."

"Apparatus claims cover what is device is, not what a device does" Hewlett-Packard versus Bausch & Lomb Inc., 15 USPQ2d 1525, 1528." Art Unit: 3663

In the underlying case, direction of movement of at least one carrier, in particular during the ON state, in said channel formation region coincides with, i.e., is parallel to, the direction of extension of said grain boundary, i.e., the direction along which said grain boundary is extended (see, for instance Figures 2B and 3F (grain boundary extended along 23, which has portions parallel to the channel between source and drain 26N (see Figure 3I, e.g.). Therefore, the device of the prior art is capable of performing the intended use.

With regard to claim 43: the semiconductor film by Iwasaki comprises silicon (see Figure 3J and discussion, especially col. 10, I. 51 and Example 2).

With regard to claim 47: the only limitation additional to those of claim 21 is "a thermal oxidation film provided between the semiconductor film and the gate electrode". First it is observed that "thermal oxidation film" does not patentably distinguish from "oxide film", because the difference is one of manufacture, not necessarily of structure. Applicant is reminded that the limitation in the present product claim is only of patentable weight in as much as the method steps distinguish the final structure, and to the extent not impacting final structure are taken to be product-by-process limitations and non-limiting. A product by process claim is directed to the product per se, no matter how they are actually made. See In re Fessman, 180 USPQ 324, 326 (CCPA 1974); In re Marosi et al, 218 USPQ 289, 292 (Fed. Cir. 1983), and In re Thorpe, 227 USPQ 964, 966 (Fed. Cir. 1985), all of which make clear that it is the patentability of the final structure of the product "gleaned" from the process steps that must be determined in a "product-by-process"

claim, and not the patentability of the process. See also MPEP 2113. Moreover, an old or obvious product produced by a new method is not a patentable product, whether claimed in "product by process" claims or not. Second, Iwasaki teaches a silicon oxide gate insulating film 10 (col. 10, I. 14-18), and hence the limitation is met.

With regard to claim 51, the direction of movements of any of the (charge) carriers has inherently two components, a random component and a component in response to the local (mainly electric) field. While the direction of said random component by its very nature is not subject to control, the component in response to the local field is a result of the operation of the device, and hence is not a limitation of the device as such.

Therefore, the limitation on the direction of movement of a carrier in said channel formation region is a statement of intended use not serving to patently distinguish the claimed structure over that of the reference as long as the structure of the cited reference is capable of performing the intended use. See MPEP 2111-2115. See also MPEP 2114 that states:

"A claim that contains a "recitation with respect to the manner in which a claimed apparatus is intended to be employed does not differentiate the claimed apparatus from a prior art apparatus" if the prior art apparatus teaches all of the structural limitations of the claim Ex parte Masham, 2 USPQd 1647.".

"Claims directed to apparatus must be distinguished from the prior art in terms of structure rather than function. In re Danly, 263 F.2d 844, 847, 120 USPQ 528, 531."

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"Apparatus claims cover what is device is, not what a device does" Hewlett-Packard versus Bausch & Lomb Inc., 15 USPQ2d 1525, 1528."

In the underlying case, direction of movement of at least one carrier, in particular during the ON state, in said channel formation region coincides with, i.e., is parallel to, the direction of extension of said grain boundary, i.e., the direction along which said grain boundary is extended (see, for instance Figures 2B and 3F (grain boundary extended along 23, which has portions parallel to the channel between source and drain 26N (see Figure 3I, e.g.). Therefore, the device of the prior art is capable of performing the intended use.

With regard to claim 52: the semiconductor film by Iwasaki comprises silicon (see Figure 3J and discussion, especially col. 10, I. 51 and Example 2).

# Claim Rejections - 35 USC § 103

- 12. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 13. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to

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consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

14. Claims 22 and 48 are rejected under 35 U.S.C. 103(a) as being unpatentable over Iwasaki in view of Erhart et al. (USPAT 5,572,211) (previously cited).

As detailed above, claim 21 and claim 47 are anticipated by Iwasaki. Iwasaki does not teach the further limitation defined by claims 22 and 48. Iwasaki does teach the inclusion of TFTs in active matrix LCD displays for computers (column 1, lines 7-20).

However, it would have been obvious to include said further limitation in view of Erhart et al, who teach the inclusion of *capacitors*, e.g., 56 and 58 (column 6, line 55 – column 6, line 15), in addition to thin film transistors e.g., 48 and 50 (column 6, lines 55-60) in an active matrix display (column 6, lines 16-55) in a *personal* computer (column 12, lines 45-49). *Motivation* to include the teaching by Erhart in the device by Iwasaki derives at least from the obvious advantage to apply the invention to improvements of existing technology, i.e., to active matrix LCD displays in personal computers wherein capacitors store charge corresponding to the desired shade for the pixel electrode to which said storage capacitor pertains (column 6, line 64 – column 7, line 4). N.B.: said capacitors imply *auxiliary* capacitance because they are not part of the TFT, i.e., not part of the MOS capacitor that is part of the TFT.

15. *Claims 23, 25, 46, 49-50 and 55* are rejected under 35 U.S.C. 103(a) as being unpatentable over Iwasaki in view of den Boer (USPAT 5,539,219) (previously cited).

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On claim 23 and 49: As detailed above, claims 21 and 47 are anticipated by Iwasaki. Iwasaki does not teach the further limitation as defined by claims 23 and 49, although Iwasaki does teach the computer (col. 1, I. 15-20) to further comprise an active matrix type liquid crystal display device (col. 1, I. 7-20). Iwasaki does not specifically recited pixel electrode and opposite electrode, with liquid crystal provided therebetween.

However, said limitation merely conforms to the conventional active matrix liquid crystal display technology, as witnessed for instance by den Boer et al., who teach an active matrix liquid crystal display device (column 1, lines 5-33) to comprise not only TFTs 21 (column 4, line 62 – column 5, line 8) but also pixel electrode 51 (column 5, lines 5-8 and column 8, lines 33-43), common electrode 59 (column 8, lines 37-39) opposite said pixel electrode and hence qualifying as "opposite" electrode (see Figure 5) with liquid crystal 57 between said pixel electrode and said opposite electrode.

\*\*Motivation\*\* to include said limitation as taught by den Boer in the invention by Iwasaki at least derives from the economy to apply the invention to already existing and hence easily marketable technology.

With regard to claims 25 and 50, Iwasaki does not specifically teach the further limitation on channel length as recited. However, it would have been obvious to include the limitation in view of den Boer, who teaches a channel length of about 2 μm to 4 μm (column 8, lines 8-19) so as to achieve a reduction in pixel flickering, image retention and an improvement in gray level uniformity (see abstract). Applicant is reminded A prima facie case of obviousness typically exists when the ranges of a claimed composition overlap the ranges disclosed in the prior art or when the ranges of a

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claimed composition do not overlap but are close enough such that one skilled in the art would have expected them to have the same properties. In re Peterson, 65 USPQ2d 1379 (CA FC 2003). In the underlying case, the range in the prior art (about 2 to 4  $\mu$ m) actually overlaps the range as claimed (less than or equal 2  $\mu$ m) while motivation immediately derives from the teaching by den Boer that the shortened channel length enables reduction in pixel flickering and image retention and an improvement in grey level uniformity.

With regard to claims 46 and 55: the pixel electrode by den Boer comprises ITO (col. 7, I. 51). Motivation derives at least from the good conductivity and transparency of ITO, both qualities being important for an electrode in the way of light.

16. Claims 44-45 and 53-54 are rejected under 35 U.S.C. 103(a) as being unpatentable over Iwasaki in view of Kobayashi (3,925,803) (previously cited).

As detailed above, claims 21 and 47 are anticipated by Iwasaki. Iwasaki does not teach the further limitations of either claim 44 or 45, nor claims 53 or 54. However, it would have been obvious to include said further limitations in view of Kobayashi, who, in a patent on a field effect transistor, - in particular: on the polycrystalline structure of the channel region therein, hence analogous art (TFTs are field effect transistors as well), teach the source/channel/drain region to comprise, within the channel region, rodshaped silicon crystals 3 (col. 2, I. 30), evidently flattened at the top (Figure 1 and discussion in col. 2). Motivation derives at least from the noted high trans-conductance (see "Summary of the Invention", col. 1).

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17. *Claims 56 and 60-61* are rejected under 35 U.S.C. 103(a) as being unpatentable over Iwasaki (JP 08-288515 A) (as cited above, again with Iwasaki (USPAT 5,759,879) used for translation) (previously cited) in view of Inoue et al (6,153,893) (previously cited).

On claim 56: Iwasaki teaches (whole document, especially title, abstract, "Field of the Invention", column 1, lines 7-20, and Examples 1-2, columns 7-12; Figures 2-3) a semiconductor film 22 (column 10, lines 45-48) over a substrate 16 (loc.cit.) and comprising a source region and drain region (both 26N; see column 10, line 50) and a channel formation region 26i (column 10, lines 49-50) provided between said source and drain regions; and a gate electrode 25 (column 10, line 55) provided adjacent to said channel formation region with a gate insulating film 24 (column 10, line 54) therebetween; wherein lattices are continuously connected to each other at a grain boundary 23 (Figure 3F and column 12, lines 17-18) of said semiconductor film, inherently so, because a grain boundary is a boundary, i.e., a line, point or plane that indicates or fixes a limit or extent, between two grains, i.e., crystal grains; said crystal grains inherently having spatial extent, as otherwise their defining property, i.e., spatial periodicity, could not possibly exist; the lines denoting the grain boundaries in Figure 3F thus denote the limits on either side of the crystal grains connected by their common grain boundaries, implying continuity across said grain boundaries; hence the lattices of said grains, extending by definition of the grains over their entire spatial domain, are continuously connected to each other at the grain boundaries of said semiconductor film.

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With regard to the claimed "first lattice images in a direction parallel to said grain boundary in the first crystal" being different from "second lattice images in the direction parallel to said grain boundary", said limitation fails to further limit the claimed "personal computer": although the claimed "first lattice images" and "second lattice images" are not necessarily taught by the prior art, said images do not belong to the claimed "personal computer" as disclosed, while any images made of said first and second lattices in the same direction parallel to the grain boundary, when made, necessarily differ because said first lattice and second lattices differ if only by being in different crystals, and hence they are distinguishable given any adequate images of said first and second lattices.

Iwasaki does not necessarily teach the limitation of "a low concentration impurity region provided between the channel formation region and at least one of the source region and the drain region".

However, it would have been obvious to include said limitation in view of Inoue et al, who, in a patent on a thin film transistor (title, abstract), hence analogous art, teach the manufacture of a lightly doped drain (LDD) structure, known to be beneficial for insulated gate field effect transistors generally, for the specific advantage of prevention of pixel leakage (col. 2, I. 23-28), from which teaching *motivation* immediately follows.

With regard to claim 60: the direction of movements of any of the (charge) carriers has inherently two components, a random component and a component in response to the local (mainly electric) field. While the direction of said random component by its very nature is not subject to control, the component in response to the

local field is a result of the operation of the device, and hence is not a limitation of the device as such. Therefore, the limitation on the direction of movement of a carrier in said channel formation region is a statement of intended use not serving to patently distinguish the claimed structure over that of the reference as long as the structure of the cited reference is capable of performing the intended use. See MPEP 2111-2115. See also MPEP 2114 that states:

"A claim that contains a "recitation with respect to the manner in which a claimed apparatus is intended to be employed does not differentiate the claimed apparatus from a prior art apparatus" if the prior art apparatus teaches all of the structural limitations of the claim Ex parte Masham, 2 USPQd 1647.".

"Claims directed to apparatus must be distinguished from the prior art in terms of structure rather than function. In re Danly, 263 F.2d 844, 847, 120 USPQ 528, 531."

"Apparatus claims cover what is device is, not what a device does" Hewlett-Packard versus Bausch & Lomb Inc., 15 USPQ2d 1525, 1528."

In the underlying case, direction of movement of at least one carrier, in particular during the ON state, in said channel formation region coincides with, i.e., is parallel to, the direction of extension of said grain boundary, i.e., the direction along which said grain boundary is extended (see, for instance Figures 2B and 3F (grain boundary extended along 23, which has portions parallel to the channel between source and drain 26N (see Figure 3I, e.g.). Therefore, the device of the prior art is capable of performing the intended use.

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With regard to claim 61: the semiconductor film by Iwasaki comprises silicon (see Figure 3J and discussion, especially col. 10, I. 51 and Example 2).

18. *Claim* 57 is rejected under 35 U.S.C. 103(a) as being unpatentable over Iwasaki and Inoue et al as applied to claim 56, in view of Erhart et al. (USPAT 5,572,211) (previously cited).

As detailed above, claim 56 is unpatentable over Iwasaki in view of Inoue et al.

Neither Iwasaki nor Inoue et al teach the further limitation defined by claim 57, although Iwasaki does teach the inclusion of TFTs in active matrix LCD displays for computers (column 1, lines 7-20).

However, it would have been obvious to include said further limitation in view of Erhart et al, who teach the inclusion of *capacitors*, e.g., 56 and 58 (column 6, line 55 – column 6, line 15), in addition to thin film transistors e.g., 48 and 50 (column 6, lines 55-60) in an active matrix display (column 6, lines 16-55) in a *personal* computer (column 12, lines 45-49). *Motivation* to include the teaching by Erhart in the device by Iwasaki derives at least from the obvious advantage to apply the invention to improvements of existing technology, i.e., to active matrix LCD displays in personal computers wherein capacitors store charge corresponding to the desired shade for the pixel electrode to which said storage capacitor pertains (column 6, line 64 – column 7, line 4). N.B.: said capacitors imply *auxiliary* capacitance because they are not part of the TFT, i.e., not part of the MOS capacitor that is part of the TFT.

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19. *Claims 58-59 and 64* are rejected under 35 U.S.C. 103(a) as being unpatentable over Iwasaki and Inoue et al as applied to claim 56, in view of den Boer (USPAT 5,539,219) (previously cited).

As detailed above, claim 56 is unpatentable over Iwasaki in view of Inoue et al.

Neither Iwasaki nor Inoue et al teach the further limitation as defined by claim 58,

although Iwasaki does teach the computer (col. 1, I. 15-20) to further comprise an active

matrix type liquid crystal display device (col. 1, I. 7-20). Iwasaki does not specifically

recited pixel electrode and opposite electrode, with liquid crystal provided therebetween.

However, said limitation merely conforms to the conventional active matrix liquid crystal display technology, as witnessed for instance by den Boer et al., who teach an active matrix liquid crystal display device (column 1, lines 5-33) to comprise not only TFTs 21 (column 4, line 62 – column 5, line 8) but also pixel electrode 51 (column 5, lines 5-8 and column 8, lines 33-43), common electrode 59 (column 8, lines 37-39) opposite said pixel electrode and hence qualifying as "opposite" electrode (see Figure 5) with liquid crystal 57 between said pixel electrode and said opposite electrode.

\*\*Motivation\*\* to include said limitation as taught by den Boer in the invention by Iwasaki at least derives from the economy to apply the invention to already existing and hence easily marketable technology.

With regard to claims 59, Iwasaki does not specifically teach the further limitation on channel length as recited. However, it would have been obvious to include the limitation in view of den Boer, who teaches a channel length of about 2  $\mu$ m to 4  $\mu$ m (column 8, lines 8-19) so as to achieve a reduction in pixel flickering, image retention and an

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improvement in gray level uniformity (see abstract). Applicant is reminded A *prima facie* case of obviousness typically exists when the ranges of a claimed composition overlap the ranges disclosed in the prior art or when the ranges of a claimed composition do not overlap but are close enough such that one skilled in the art would have expected them to have the same properties. In re Peterson, 65 USPQ2d 1379 (CA FC 2003). In the underlying case, the range in the prior art (about 2 to 4  $\mu$ m) actually overlaps the range as claimed (less than or equal 2  $\mu$ m) while motivation immediately derives from the teaching by den Boer that the shortened channel length enables reduction in pixel flickering and image retention and an improvement in grey level uniformity.

With regard to claim 64: the pixel electrode by den Boer comprises ITO (col. 7, I. 51). Motivation derives at least from the good conductivity and transparency of ITO, both qualities being important for an electrode in the way of light.

20. Claims 62-63 are rejected under 35 U.S.C. 103(a) as being unpatentable over Iwasaki and Inoue et al as applied to claim 56, in view of Kobayashi (3,925,803). As detailed above, claim 56 is unpatentable over Iwasaki in view of Inoue et al. Neither Iwasaki nor Inoue et al teach the further limitation of claims 62 or 63. However, it would have been obvious to include said further limitations in view of Kobayashi, who, in a patent on a field effect transistor, - in particular: on the polycrystalline structure of the channel region therein, hence analogous art (TFTs are field effect transistors as well), teach the source/channel/drain region to comprise, within the channel region, rod-shaped silicon crystals 3 (col. 2, I. 30), evidently flattened at the top (Figure 1 and

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discussion in col. 2). *Motivation* derives at least from the noted high trans-conductance (see "Summary of the Invention", col. 1).

21. *Claims 68-70* are rejected under 35 U.S.C. 103(a) as being unpatentable over lwasaki in view of Tran et al (5,534,445).

As detailed above, claim 21 is anticipated by Iwasaki. Iwasaki does not teach the further limitation defined by claim 68.

However, with regard to claim 68, it would have been obvious to include said further limitation in view of Tran et al, who, in a patent on polysilicon-based thin film transistors, teach to select a silicon wafer for providing a substrate underneath the insulating layer on which the semiconductor film is grown (Figure 1 and col. 4, I. 3-7). *Motivation* to include the teaching by Tran et al derives from the suitability of silicon wafers in the art of integrated circuitry in which the thin film transistors are often used and which is shown by Tran et al to be compatible with very low current leakage (abstract and "Detailed Description of the Invention").

Furthermore, with regard to claim 69, it would have been obvious to include said further limitation in view of Tran et al, who, in a patent on polysilicon-based thin film transistors, teach to select a silicon wafer for providing a substrate underneath the insulating layer on which the semiconductor film is grown (Figure 1 and col. 4, I. 3-7). *Motivation* to include the teaching by Tran et al derives from the suitability of silicon wafers in the art of integrated circuitry in which the thin film transistors are often used and which is shown by Tran et al to be compatible with very low current leakage (abstract and "Detailed Description of the Invention").

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Finally, with regard to claim 70, it would have been obvious to include said further limitation in view of Tran et al, who, in a patent on polysilicon-based thin film transistors, teach to select a silicon wafer for providing a substrate underneath the insulating layer on which the semiconductor film is grown (Figure 1 and col. 4, I. 3-7). Motivation to include the teaching by Tran et al derives from the suitability of silicon wafers in the art of integrated circuitry in which the thin film transistors are often used and which is shown by Tran et al to be compatible with very low current leakage (abstract and "Detailed Description of the Invention").

### **Double Patenting**

22. The nonstatutory double patenting rejection is based on a judicially created doctrine grounded in public policy (a policy reflected in the statute) so as to prevent the unjustified or improper timewise extension of the "right to exclude" granted by a patent and to prevent possible harassment by multiple assignees. A nonstatutory obviousness-type double patenting rejection is appropriate where the conflicting claims are not identical, but at least one examined application claim is not patentably distinct from the reference claim(s) because the examined application claim is either anticipated by, or would have been obvious over, the reference claim(s). See, e.g., *In re Berg*, 140 F.3d 1428, 46 USPQ2d 1226 (Fed. Cir. 1998); *In re Goodman*, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); *In re Longi*, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985); *In re Van Ornum*, 686 F.2d 937, 214 USPQ 761 (CCPA 1982); *In re Vogel*, 422 F.2d 438, 164 USPQ 619 (CCPA 1970); and *In re Thorington*, 418 F.2d 528, 163 USPQ 644 (CCPA 1969).

A timely filed terminal disclaimer in compliance with 37 CFR 1.321(c) or 1.321(d) may be used to overcome an actual or provisional rejection based on a nonstatutory double patenting ground provided the conflicting application or patent either is shown to be commonly owned with this application, or claims an invention made as a result of activities undertaken within the scope of a joint research agreement.

Effective January 1, 1994, a registered attorney or agent of record may sign a terminal disclaimer. A terminal disclaimer signed by the assignee must fully comply with 37 CFR 3.73(b).

23. *Claims 21, 44 and 45* are rejected on the ground of non-statutory obviousness double patenting as being unpatentable over claim 5 of US Patent 6,380,560 B1. An obviousness-type double patenting rejection is appropriate where the conflicting claims

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are not identical, but an examined application claim is not patentably distinct from the reference claims because the examined claim is either anticipated by, or would be obvious over, the reference claims. See, e.g., In re Berg 140 F.3d 1428, 46 USPQ2d 1226 (Fed. Cir. 1998); In re Goodman, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); In re Longi, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985). Although the conflicting claims are not identical, they are not patentably distinct from each other because claim 21 is generic to all that is recited in claim 5 of US Patent 6,380,560. In other words, claim 5 of US Patent 6,380,560 fully and explicitly encompasses the subject matter of claim 1 of the current application. Within the Markush claim 5 the selection "personal computer" for the claimed semiconductor device renders claim 21 fully encompassed by the limitations of its independent claim 1, because of the following mapping:

- Semiconductor film in claim 21: semiconductor film in claim 5 through claim 1.
- Substrate in claim 21: <u>anticipated</u> by "single crystal semiconductor wafer"
  in claim 5 through claim 1, said single crystal semiconductor wafer being a
  special kind of substrate.
- Source region, drain region and channel formation region of claim 21:
   idem claim 5 through claim 1.
- Gate electrode adjacent said channel formation region with a gate
   insulating film therebetween in claim 21: idem claim 5 through claim 1.

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The limitation "wherein lattice are continuously connected to each other at
a grain boundary of said semiconductor film" in claim 21: is <u>anticipated</u>
through the limitation "wherein lattices are continuously connected to each
other at substantially all of said grain boundary according to high
resolution TEM", with said "grain boundary being defined by "adjacent two
crystals"

- With regard to claims 44 and 45, their limitations are also <u>anticipated</u> by those of claims 6 and 7 of 6,380,560, because said two crystals having said grain boundary are comprised in the semiconductor film.
- Finally, the limitation "first lattice images in a direction parallel to said grain boundary in the first crystal are different from second lattice images in the direction parallel to said grain boundary in the second crystal" in applicant's claim 21 fails to further limit the "personal computer" and is inherently met by any two images of said first and second lattice, because any such images will show different lattices, distinguished if only by being distinct lattice with different location, i.e., on two different sides of the grain boundary.

### Conclusion

24. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP

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§ 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to JOHANNES P. MONDT whose telephone number is (571)272-1919. The examiner can normally be reached on 7:30 - 17:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Jack W. Keith can be reached on 571-272-6878. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/Johannes P Mondt/ Primary Examiner, Art Unit 3663